



NPN TRIPLE DIFFUSED PLANAR SILICON TRANSISTOR

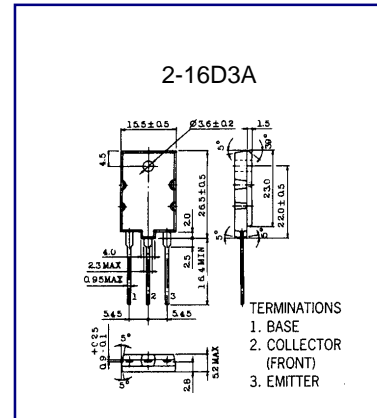
2SD1426

**COLOR TV HORIZONTAL OUTPUT
APPLICATIONS(Damper Diode BUILT IN)**

- High Collector-Base Voltage($V_{CB0}=1500V$)
- High Speed Switching

ABSOLUTE MAXIMUM RATINGS ($T_A=25^{\circ}C$)

Characteristic	Symbol	Rating	Unit
Collector-Base Voltage	V_{CB0}	1500	V
Collector-Emmitter Voltage	V_{CEO}	1500	V
Emmitter-Base voltage	V_{EBO}	6	V
Collector Current (DC)	I_C	3.5	A
Collector Dissipation ($T_c=25^{\circ}C$)	P_C	50	W
Junction Temperature	T_j	150	$^{\circ}C$
Storage Temperature	T_{stg}	-50~150	$^{\circ}C$



ELECTRICAL CHARACTERISTICS ($T_A=25^{\circ}C$)

Characteristic	Symbol	Test Condition	Min	Typ	Max	Unit
Collector- Emmitter Cutoff Current($V_{BE}=0$)	I_{CES}	$V_{CE}= 1400 V$,			1.0	mA
Collector Cutoff Current	I_{CBO}	$R_{BE}=0$			10	μA
Emmitter Cutoff Current	I_{EBO}	$V_{CB}= 800 V$, $I_E=0$			1.0	mA
DC Current Gain	h_{FE}	$V_{EB}= 4V$, $I_C=0$	8			
Collector- Emmitter Saturation Voltage	$V_{CE(sat)}$	$V_{CE}= 5V$, $I_C=1A$, $I_C=3A$, $I_B=0.8A$			8.0	V